

THE AH3391Q IS NOT RECOMMENDED FOR NEW DESIGNS. PLEASE USE THE AH3321Q.

AH3391Q



HIGH-VOLTAGE LOW-SENSITIVITY AUTOMOTIVE HALL-EFFECT UNIPOLAR SWITCH

Description

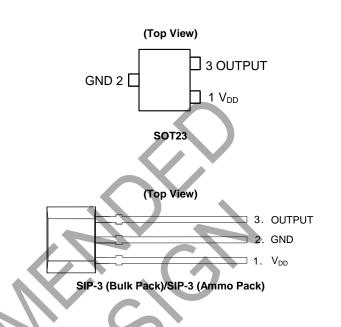
The AH3391Q is an AEC-Q100 qualified high-voltage low-sensitivity Hall-effect Unipolar switch IC designed for position and proximity sensing in automotive applications such as in seat and seatbelt buckle, steering lock/immobilisation, gear stick, transmission actuator and gear position, HVAC compression, wiper, door/trunk closure, etc. To support the wide range of the demanding applications, the design has been optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3391Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an overcurrent limit and a Zener clamp.

The single open-drain output can be switched on with South pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (BOP) the output is switched on (pulled low) and is held on until the magnetic flux density B is lower than the release point (BRP). The output remains switched off for North pole fields to or no magnetic fields.

Features

- Unipolar Operation
- Medium Sensitivity: BOP and BRP of 275G and 250G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- **Chopper Stabilized Design Provides**
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM > 8kV. CDM: > 2kV
- AEC-Q100 Grade 0 Qualified
- Industry Standard SOT23, SIP-3 (Ammo Pack) and SIP-3 (Bulk Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The AH3391Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/guality/product-definitions/



Applications

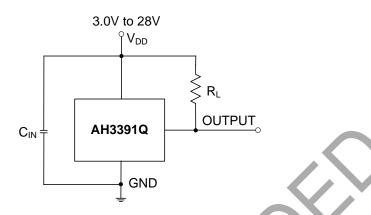
- Position and proximity sensing in automotive applications
- Seat positions
- Seatbelt buckles
- Steering locks/immobilisation
- Gear sticks
- **HVAC** compression
- Transmission actuators
- Transmission gear positions
- Wipers
- Sunroofs and windows
- Door/trunk closure
- Door locks
- Contactless switches

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments



Typical Applications Circuit (Note 4)



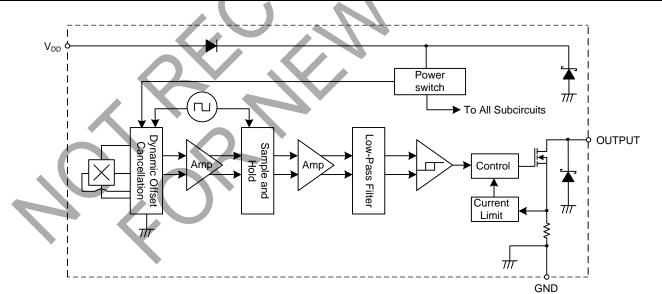
Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF to 100nF. R_L is the pullup resistor.

Pin Descriptions

Packages: SOT23, SIP-3 (Ammo Pack) and SIP-3 (Bulk Pack)

Pin Number	Pin Name	Function
1	Vdd	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

Functional Block Diagram





Symbol	Characteristic	Value	Unit				
Vdd	Supply Voltage (Note 6)	Supply Voltage (Note 6)					
Vddr	Reverse Supply Voltage (Note 6)		-32	V			
Vout_max	Output Off Voltage (Note 6)		32	V			
Іоит	Continuous Output Current	Continuous Output Current					
IOUT_R	Reverse Output Current	-50					
В	Magnetic Flux Density	Unlimited					
PD	Package Power Dissipation	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	550	mW			
2	5	SOT23	230				
Ts	Storage Temperature Range		-65 to +165	°C			
TJ	Maximum Junction Temperature	+150	°C				
ESD HBM	Electros Static Discharge Withstand - Human Boo	8	kV				
ESD MM	Electros Static Discharge Withstand - Machine Mo	odel (MM)	800	V			
ESD CDM	Electros Static Discharge Withstand - Charged De	evice Model (CDM)	2	kV			

Absolute Maximum Ratings (Notes 5 & 6) (@TA = +25°C, unless otherwise specified.)

Notes: 5. Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to *Absolute Maximum Ratings* for extended periods can affect device reliability.

6. The absolute maximum V_{DD} of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

Recommended Operating Conditions (@TA = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit	
V _{DD}	Supply Voltage	Operating	3.0 to 28	V
TA	Operating Temperature Range	Operating	-40 to +150	°C

Electrical Characteristics (Notes 7 & 8) (@T_A = -40°C to +150°C, V_{DD} = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Vout_on	Output ON Voltage	I _{OUT} = 20mA, B > B _{OP}	_	0.2	0.4	V
Ilkg	Output Leakage Current (When output is off)	Vout = 28V, B < B _{RP} , Output off	_	< 0.1	10	μA
IDD	Supply Current	Output open, $T_A = +25^{\circ}C$	_	3	3.5	mA
IDD	Supply Cultern	Output open, T _A = -40°C to +150°C	_		4	mA
		V _{DD} = -18V, T _A = +25°C	—	0.6		μA
1	Poveras Supply Current	V _{DD} = -18V, T _A = -40°C to +150°C	_	0.6	1500	μA
IDD_R	Reverse Supply Current	V _{DD} = -28V, T _A = +25°C	—	1.6		μA
		$V_{DD} = -28V, T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	_	1.6	2500	μA
tp_on	Device Power-On Time (Startup time)	$V_{DD} \ge 3V, B > B_{OP}$ (Note 7)	_	10	_	μs
fc	Chopping Frequency	—	_	800	_	kHz
to	Response Time Delay (Time from magnetic threshold reached to the start of the output rise or fall)	(Note 9)	_	3.75	_	μs
tR	Output Rising Time (External pullup resistor RL and load capacitance dependent)	R _L = 1kΩ, C _L = 20pF	_	0.2	1	μs
tF	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega$, $C_L = 20pF$	_	0.1	1	μs
locl	Output Current Limit	B > BOP (Note 10)	30		55	mA
Vz	Zener Clamp Voltage	IDD = 5mA	28	_	_	V

Notes: 7. When power is initially turned on, Vbb must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.

 Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

9. Guaranteed by design, process control and characterization. Not tested in production.

10. The device will limit the output current I_{OUT} to current limit of I_{OCL} .



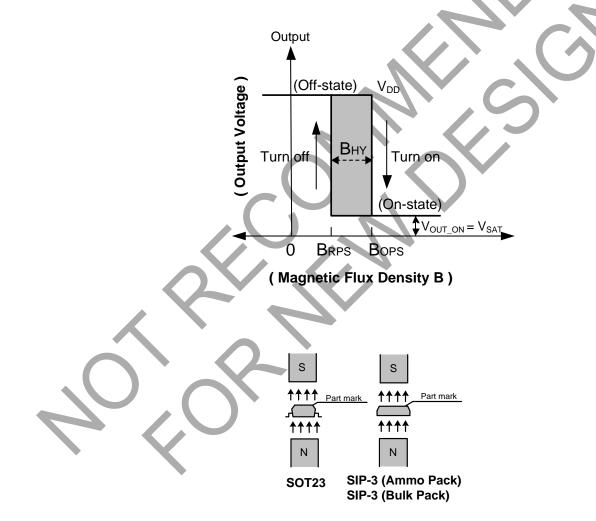
Magnetic Characteristics (Notes 11 & 12) (T_A = -40°C to +150°C, V_{DD} = 3.0V to 28V, unless otherwise specified.)

				(1m	nT = 10 Ga	auss)
Symbol	Parameter	Condition	Min	Тур	Max	Unit
Bops		V _{DD} = 12V, T _A = +25°C	_	275		
(South pole to the part marking side of SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) packages)	Operation Point	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	235	275	300	
BRPS		$V_{DD} = 12V, T_A = +25^{\circ}C$	—	250	_	0.000
(South pole to the part marking side of SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) packages)	Release Point	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	210	250	275	Gauss
	Hystoropia (Noto 12)	$V_{DD} = 12V, T_A = +25^{\circ}C$		25	_	
Bhy (Bopx - Brpx)	Hysteresis (Note 13)	T _A = -40°C to +150°C	17	25	36	

Notes: 11. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.

 Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

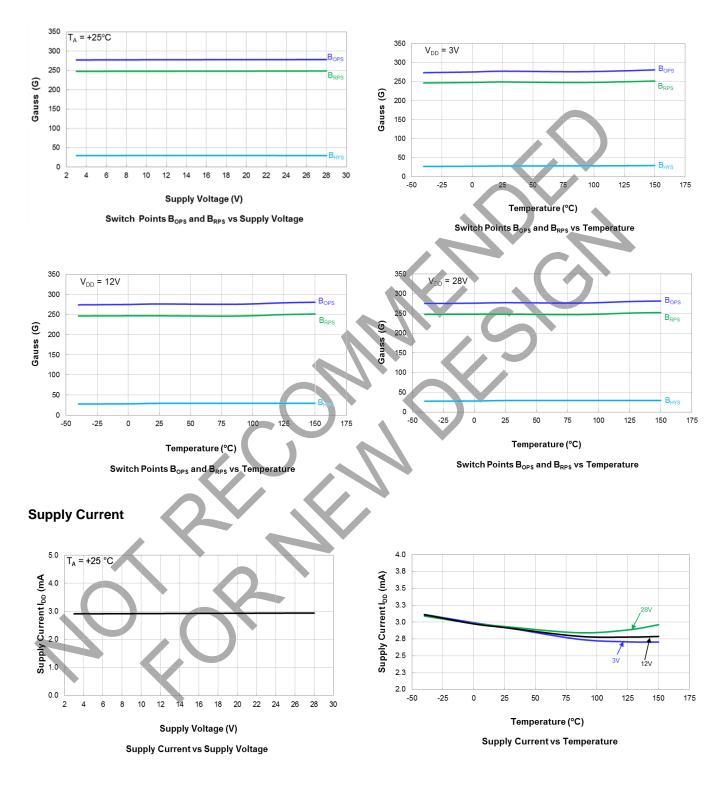
13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.





Typical Operating Characteristics

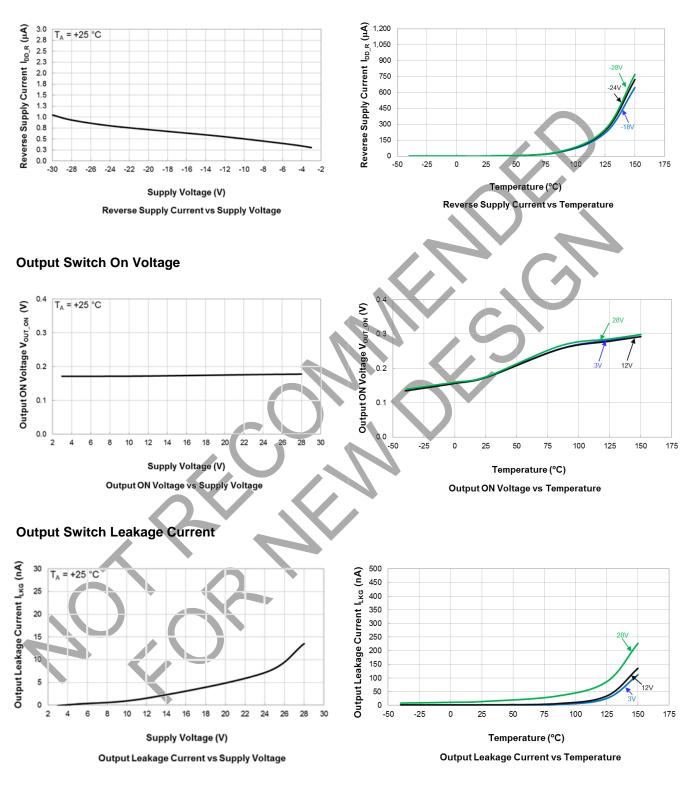
Output Switch Operate and Release Points (Magnetic Thresholds) - BOPS and BRPS





Typical Operating Characteristics (continued)

Supply Reverse Current





Typical Operating Characteristics (continued)

Output Current Limit

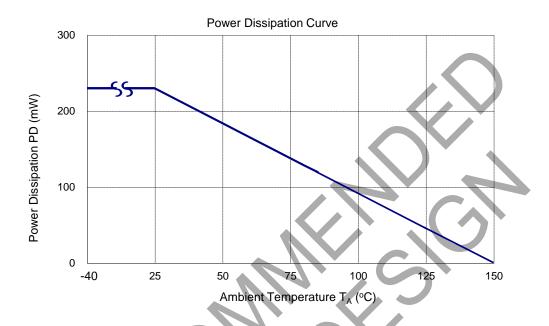




Thermal Performance Characteristics

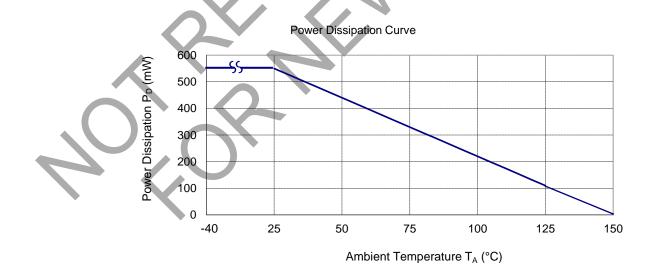
(1) Package Type: SOT23

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



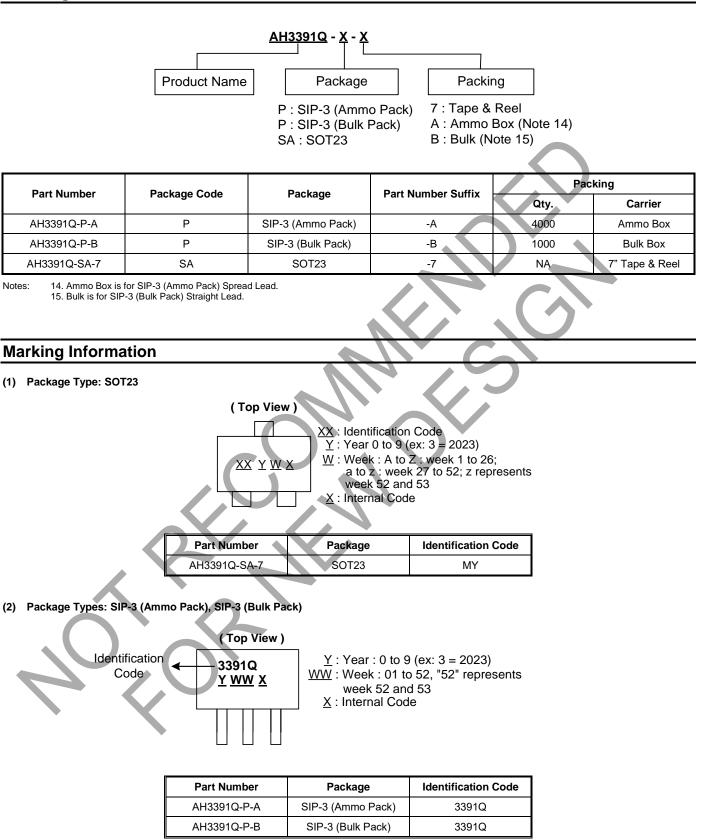
(2) Package Types: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





Ordering Information

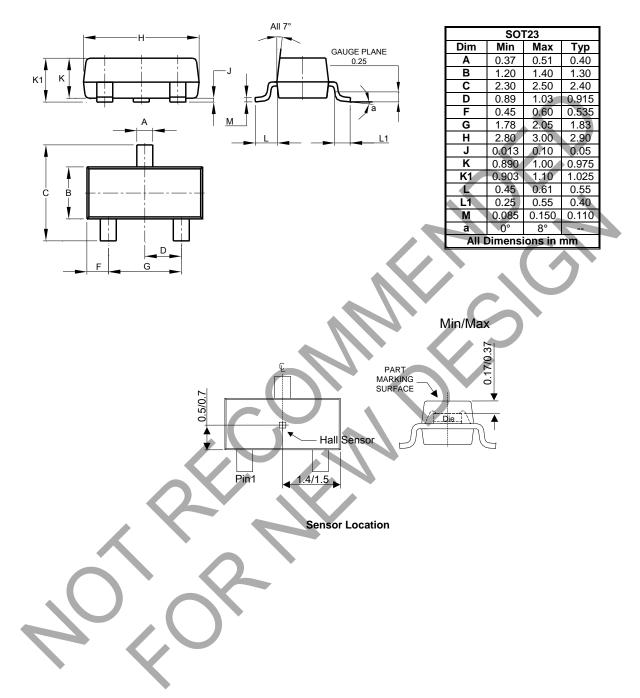




Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT23

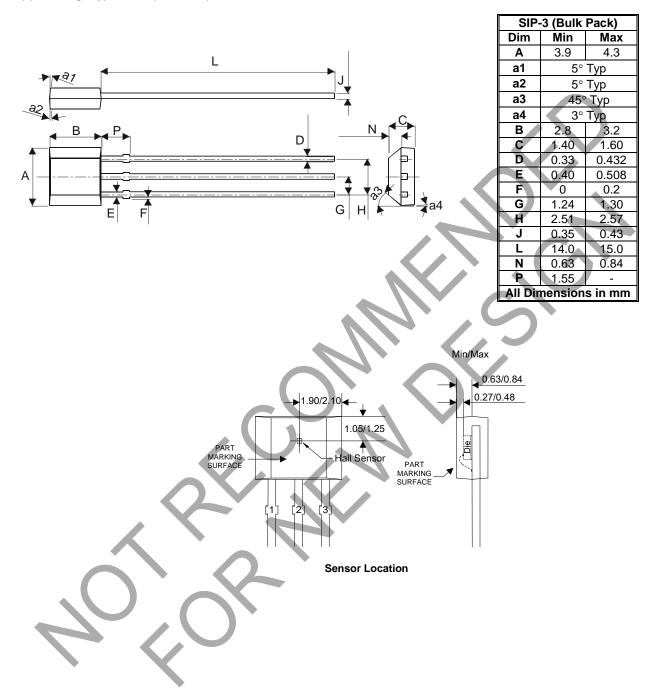




Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: SIP-3 (Bulk Pack)

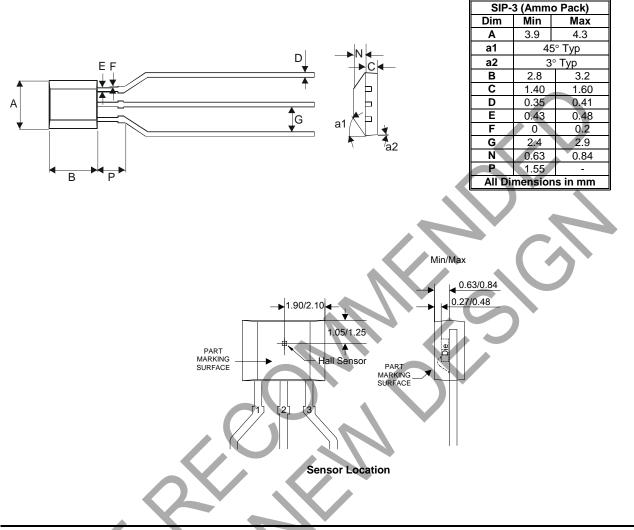




Package Outline Dimensions (continued) (All dimensions in mm.)

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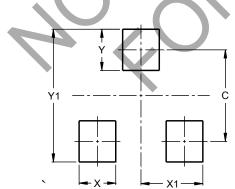
(3) Package Type: SIP-3 (Ammo Pack)



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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